



**TRANSISTORS, POWER, NPN,  
BASED ON TYPE 2N3599  
ESCC Detail Specification No. 5208/006**

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**TRANSISTORS, POWER, NPN**

**BASED ON TYPE 2N3599**

**ESA/SCC Detail Specification No. 5208/006**



**space components  
coordination group**

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**DOCUMENTATION CHANGE NOTICE**

Rev. Letter	Rev. Date	Reference	CHANGE Item	Approved DCR No.		
'A'	Feb. '92	This Issue incorporates all modifications agreed on the basis of Policy DCR 21016 for adaptation to new qualification requirements.				
		P1.	Cover page	None		
		P2.	DCN	None		
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		P6.	Table 1(a)	: "Lead Material and/or Finish" column amended	21025	
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			Para. 4.1	: Additional text added	21019	
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		P13.	Para. 4.4.2	: Paragraph amended	21025	
		P18.	Table 3(a), (b)	: Reference to Note 2 deleted, Note 1 put under this table	21047	
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**APPENDICES (Applicable to specific Manufacturers only)**

None.

**1. GENERAL****1.1 SCOPE**

This specification details the ratings, physical and electrical characteristics, test and inspection data for a Transistor, Power, NPN, based on Type 2N3599.

It shall be read in conjunction with ESA/SCC Generic Specification No. 5000, the requirements of which are supplemented herein.

**1.2 COMPONENT TYPE VARIANTS**

See Table 1(a).

**1.3 MAXIMUM RATINGS**

The maximum ratings, which shall not be exceeded at any time during use or storage, applicable to the transistors specified herein are scheduled in Table 1(b).

**1.4 PARAMETER DERATING INFORMATION**

The derating information applicable to the transistors specified herein is shown in Figure 1.

**1.5 PHYSICAL DIMENSIONS**

The physical dimensions of the transistors specified herein are shown in Figure 2.

**1.6 FUNCTIONAL DIAGRAM**

The functional diagram showing lead identification, of the transistors specified herein, is shown in Figure 3.

**1.7 HIGH TEMPERATURE TEST PRECAUTIONS**

For tin-lead plated or solder-dipped lead finish, all tests to be performed at a temperature that exceeds + 125°C shall be carried out in a 100% inert atmosphere.

**1.8 BERYLLIUM OXIDE WARNING**

THESE COMPONENTS CONTAIN BERYLLIUM OXIDE, THE DUST OF WHICH IS HIGHLY TOXIC. DISPOSAL BY WAY OF PUBLIC WASTE SYSTEMS IS STRICTLY FORBIDDEN.



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**TABLE 1(a) - TYPE VARIANTS**

VARIANT	CASE	FIGURE	LEAD MATERIAL AND FINISH
01	TO61	2	D2
02	TO61	2	D3 or D4



**TABLE 1(b) - MAXIMUM RATINGS**

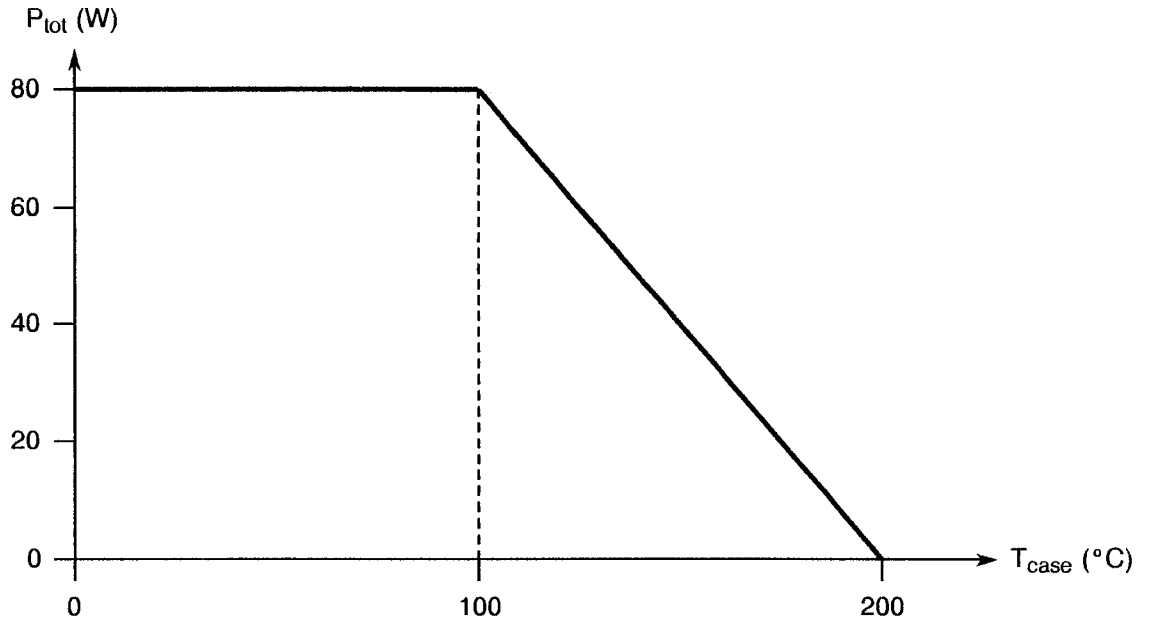
No.	CHARACTERISTICS	SYMBOL	MAXIMUM RATINGS	UNIT	REMARKS
1	Collector-Base Voltage	$V_{CB}$	100	Vdc	
2	Collector-Emitter Voltage	$V_{CE}$	80	Vdc	
3	Emitter-Base Voltage	$V_{EB}$	8.0	Vdc	
4	Collector Current (Continuous)	$I_C$	20	Adc	
5	Power Dissipation (Continuous)	$P_{tot}$	80	W	$V_{CE} = 40Vdc$ Note 1
6	Operating Temperature Range	$T_{op}$	- 65 to +200	°C	$T_{case}$
7	Storage Temperature Range	$T_{stg}$	- 65 to +200	°C	
8	Soldering Temperature	$T_{sol}$	+ 260	°C	Note 2

**NOTES**

1. For derating at  $T_{case} > +100^{\circ}C$ , see Figure 1.
2. Duration 10 seconds maximum at a distance of not less than 1.5mm from the device body and the same lead shall not be resoldered until 3 minutes have elapsed.



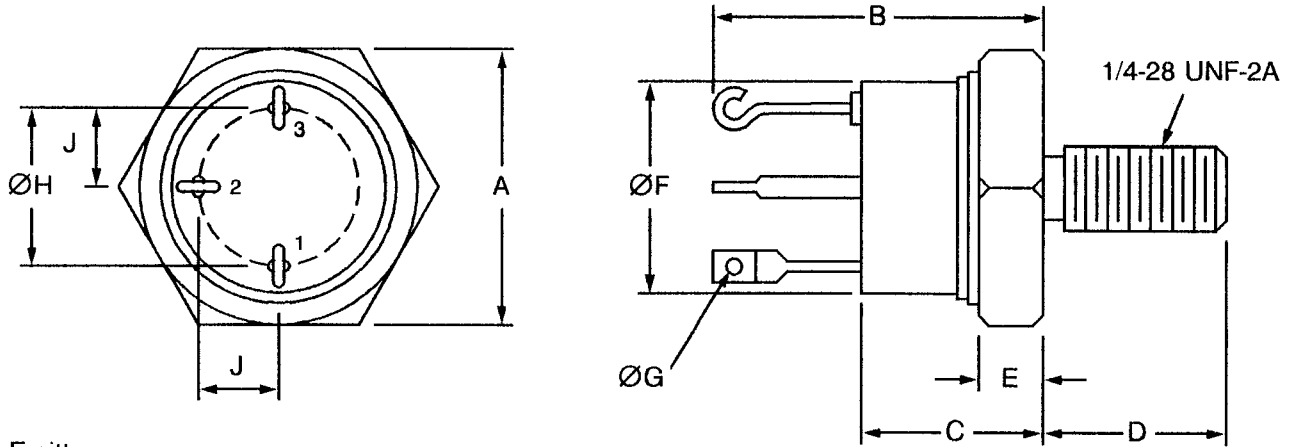
**FIGURE 1 - PARAMETER DERATING INFORMATION**



Power Dissipation versus Temperature



**FIGURE 2 - PHYSICAL DIMENSIONS**

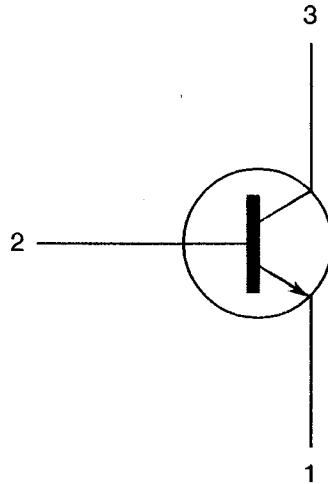


- 1. Emitter.
- 2. Base.
- 3. Collector.

SYMBOL	INCHES		MILLIMETRES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	0.677	0.687	17.20	17.45	
B	0.720	0.790	18.29	20.07	
C	0.385	0.440	9.78	11.18	
D	0.425	0.455	10.80	11.56	
E	-	0.090	-	2.29	
ØF	0.590	0.610	14.99	15.50	
ØG	0.054	0.068	1.37	1.73	
ØH	0.385	0.415	9.78	10.54	
J	0.170	0.213	4.25	5.41	
K	0.105	0.125	2.67	3.18	





**FIGURE 3 - FUNCTIONAL DIAGRAM**



- 1. Emitter.
- 2. Base.
- 3. Collector.

**NOTES**

- 1. The collector is electrically isolated from the case.

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**2. APPLICABLE DOCUMENTS**

The following documents form part of this specification and shall be read in conjunction with it:-

- (a) ESA/SCC Generic Specification No. 5000 for Discrete Semiconductor Components.
- (b) MIL-STD-750, Test Methods and Procedures for Semiconductor Devices.
- (c) ESA/SCC Basic Specification No. 23500, Requirements for Lead Materials and Finishes for Components for Space Application.
- (d) MIL-STD-105, Sampling Procedure and Tables for Inspection by Attributes.
- (e) MIL-STD-883, Test Methods and Procedures for Microelectronics.

**3. TERMS, DEFINITIONS, ABBREVIATIONS, SYMBOLS AND UNITS**

For the purpose of this specification, the terms, definitions, abbreviations, symbols and units specified in ESA/SCC Basic Specification No. 21300 shall apply.

**4. REQUIREMENTS**

**4.1 GENERAL**

The complete requirements for procurement of the transistors specified herein are stated in this specification and ESA/SCC Generic Specification No. 5000. Deviations from the Generic Specification, applicable to this specification only, are listed in Para. 4.2.

Deviations from the applicable Generic Specification and this Detail Specification, formally agreed with specific Manufacturers on the basis that the alternative requirements are equivalent to the ESA/SCC requirements and do not affect the components' reliability, are listed in the appendices attached to this specification.

**4.2 DEVIATIONS FROM GENERIC SPECIFICATION**

**4.2.1 Deviations from Special In-process Controls**

None.

**4.2.2 Deviations from Final Production Tests (Chart II)**

- (a) Add the following test, after Para. 9.2.1, "Bond Strength Test": Die Shear Test in accordance with MIL-STD-883 Method 2019, to be performed on 3 devices with no failures permitted.
- (b) Para. 9.6, "Constant Acceleration": Change Acceleration Level to 10000g.



4.2.3 Deviations from Burn-in and Electrical Measurements (Chart III)

(a) Para. 7.1.1(a), High Temperature Reverse Bias test: Not applicable.

4.2.4 Deviations from Qualification Tests (Chart IV)

None.

4.2.5 Deviations from Lot Acceptance Tests (Chart V)

None.

4.3 MECHANICAL REQUIREMENTS

4.3.1 Dimension Check

The dimensions of the transistors specified herein shall be checked. They shall conform to those shown in Figure 2.

4.3.2 Weight

The maximum weight of the transistors specified herein shall be 18 grammes.



#### 4.3.3 Terminal Strength

The requirements for terminal strength testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The test conditions shall be as follows:-

**Terminal:**

Test Condition: 'A' (Tension).  
Applied Force: 10 lb.f.  
Duration: 15 seconds.

**Stud:**

Test Condition: 'D2' (Stud Torque).  
Applied Torque: 20 lb.f.in.  
Duration: 15 seconds.

#### 4.4 MATERIALS AND FINISHES

The materials and finishes shall be as specified herein. Where a definite material is not specified, a material which will enable the transistors specified herein to meet the performance requirements of this specification shall be used. Acceptance or approval of any constituent material does not guarantee acceptance of the finished product.

##### 4.4.1 Case

The case shall be hermetically sealed and have a metal body with hard glass seals and the lid shall be welded, brazed or preform soldered.

##### 4.4.2 Lead Material and Finish

The lead material shall be Type 'D' with either Type '2' or Type '3 or 4' finish in accordance with the requirements of ESA/SCC Basic Specification No. 23500. (See Table 1(a) for Type Variants).

#### 4.5 MARKING

##### 4.5.1 General

The marking of all components delivered to this specification shall be in accordance with the requirements of ESA/SCC Basic Specification No. 21700. Each component shall be marked in respect of:-

- (a) The SCC Component Number.
- (b) Traceability Information.

##### 4.5.2 Lead Identification

Leads shall be positioned as shown in Figure 2. No lead identification shall be marked on the part.



#### 4.5.3 The SCC Component Number

Each component shall bear the SCC Component Number which shall be constituted and marked as follows:-

520800602B

Detail Specification Number \_\_\_\_\_

Type Variant (see Table 1(a)) \_\_\_\_\_

Testing Level (B or C, as applicable) \_\_\_\_\_

#### 4.5.4 Traceability Information

Each component shall be marked in respect of traceability information in accordance with the requirements of ESA/SCC Basic Specification No. 21700.

#### 4.5.5 Marking of Small Components

When it is considered that the component is too small to accommodate the marking as specified above, as much as space permits shall be marked. The order of precedence shall be as follows:-

- (a) Lead Identification.
- (b) The SCC Component Number.
- (c) Traceability Information.

The marking information in full shall accompany each component in its primary package.

### 4.6 ELECTRICAL MEASUREMENTS

#### 4.6.1 Electrical Measurements at Room Temperature

The parameters to be measured at room temperature are scheduled in Table 2. Unless otherwise specified, measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.

#### 4.6.2 Electrical Measurements at High and Low Temperatures

The parameters to be measured at high and low temperatures are scheduled in Table 3. The measurements shall be performed at  $T_{amb} = -55(+5-0)$  and  $+150(+0-5)$  °C respectively.





#### 4.6.3 Circuits for Electrical Measurements

Circuits for use in performing the electrical measurements listed in Tables 2 and 3 are shown, where applicable, in MIL-STD-750 and in Figure 4 of this specification.

#### 4.7 BURN-IN TESTS

##### 4.7.1 Parameter Drift Values

The parameter drift values applicable to burn-in are specified in Table 4 of this specification. Unless otherwise stated, measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C. The parameter drift values ( $\Delta$ ) applicable to the parameters scheduled shall not be exceeded. In addition to these drift value requirements, the appropriate limit value specified for a given parameter in Table 2 shall not be exceeded.

##### 4.7.2 Conditions for Burn-in

The requirements for burn-in are specified in Section 7 of ESA/SCC Generic Specification No. 5000. The conditions for burn-in shall be as specified in Table 5 of this specification.

##### 4.7.3 Electrical Circuits for Burn-in

Not applicable.



**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - d.c. PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
1	Collector-Base Breakdown Voltage	$BV_{CBO}$	3001 Bias Cond. D	$I_C = 100\mu\text{Adc}$ $I_E = 0\text{Adc}$	100	-	V
2	Collector-Emitter Breakdown Voltage	$BV_{CES}$	3011 Bias Cond. C	$I_C = 1.0\text{mAdc}$ $V_{BE} = 0\text{Adc}$	100	-	V
3	Emitter-Base Breakdown Voltage	$BV_{EBO}$	3026 Bias Cond. D	$I_E = 1.0\text{mAdc}$ $I_C = 0\text{Adc}$	8.0	-	V
4	Collector Cut-off Current	$I_{CES}$	3041 Bias Cond. C	$V_{CE} = 60\text{Vdc}$ $V_{BE} = 0\text{Vdc}$	-	100	nA
5	Emitter Cut-off Current	$I_{EBO}$	3061 Bias Cond. D	$V_{BE} = 5.0\text{Vdc}$ $I_C = 0\text{Adc}$	-	100	nA
6	Collector Saturation Voltage	$V_{CE(SAT)}$	3071	$I_C = 10\text{Adc}$ $I_B = 1.0\text{Adc}$ Note 1	-	0.5	V
7	Base Saturation Voltage	$V_{BE(SAT)}$	3066	$I_C = 10\text{Adc}$ $I_B = 1.0\text{Adc}$ Note 1	-	1.5	V
8	D.C. Forward Current Transfer Ratio 1	$h_{FE1}$	3076	$V_{CE} = 5.0\text{Vdc}$ $I_C = 100\text{mAdc}$ Note 1	90	-	-
9	D.C. Forward Current Transfer Ratio 2	$h_{FE2}$	3076	$V_{CE} = 5.0\text{Vdc}$ $I_C = 5.0\text{Adc}$ Note 1	80	240	-
10	D.C. Forward Current Transfer Ratio 3	$h_{FE3}$	3076	$V_{CE} = 5.0\text{Vdc}$ $I_C = 10\text{Adc}$ Note 1	60	-	-

**NOTES:** See Page 17.



**TABLE 2 - ELECTRICAL MEASUREMENTS AT ROOM TEMPERATURE - a.c. PARAMETERS**

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST FIG.	TEST CONDITIONS (NOTE 2)	LIMITS		UNIT
						MIN	MAX	
11	High Frequency Forward Current Gain	$h_{fe}$	3206	-	$V_{CE} = 10Vdc$ $I_C = 2.0Adc$ $f = 10MHz$	3.0	-	-
12	Output Capacitance	$C_{obo}$	3236	-	$V_{CB} = 10Vdc$ $I_E = 0Adc$ $f = 0.1MHz$	-	700	pF
13	Input Capacitance	$C_{ibo}$	3240	-	$V_{EB} = 0.5Vdc$	-	3000	pF
14	Turn On Time	$t_{on}$	-	4(a)	$I_C = 10Adc$ $I_{B1} = I_{B2} = 1.0Adc$	-	0.5	$\mu s$
15	Turn Off Time	$t_{off}$	-	4(b)	$I_C = 10Adc$ $I_{B1} = I_{B2} = 1.0Adc$	-	2.1	$\mu s$

**NOTES**

1. Pulsed measurement: Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2.0\%$ .
2. If more than 20 units have to be measured, the measurements shall be made on a sample basis in accordance with Level II, Table IIa, with an AQL = 1.0% of MIL-STD-105.

**TABLE 3 - ELECTRICAL MEASUREMENTS AT HIGH AND LOW TEMPERATURES**TABLE 3(a) -  $T_{amb} = +150(+0 - 5) ^\circ\text{C}$ 

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
4	Collector Cut-off Current	$I_{CES}$	3036 Bias Cond. D	$T_{amb} = +150^\circ\text{C}$ $V_{CE} = 60\text{Vdc}$ $V_{BE} = 0\text{Vdc}$	-	1.0	mA

TABLE 3(b) -  $T_{amb} = -55(+5 - 0) ^\circ\text{C}$ 

No.	CHARACTERISTICS	SYMBOL	MIL-STD-750 TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN	MAX	
9	D.C. Forward Current Transfer Ratio 2	$h_{FE2}$	3076	$T_{amb} = -55^\circ\text{C}$ $I_C = 5.0\text{Adc}$ $V_{CE} = 5.0\text{Vdc}$ Note 1	40	120	-

**NOTES**

1. Pulsed measurement: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .



**FIGURE 4 - CIRCUITS FOR ELECTRICAL MEASUREMENTS**

FIGURE 4(a) - TURN-ON TIME

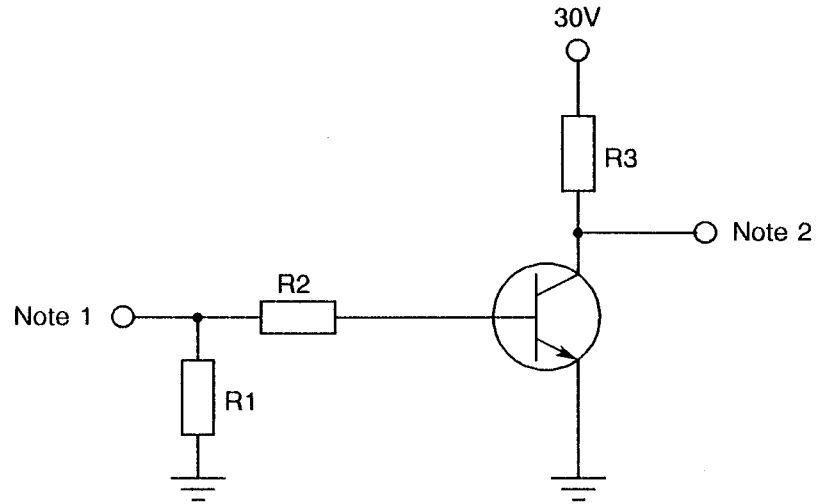
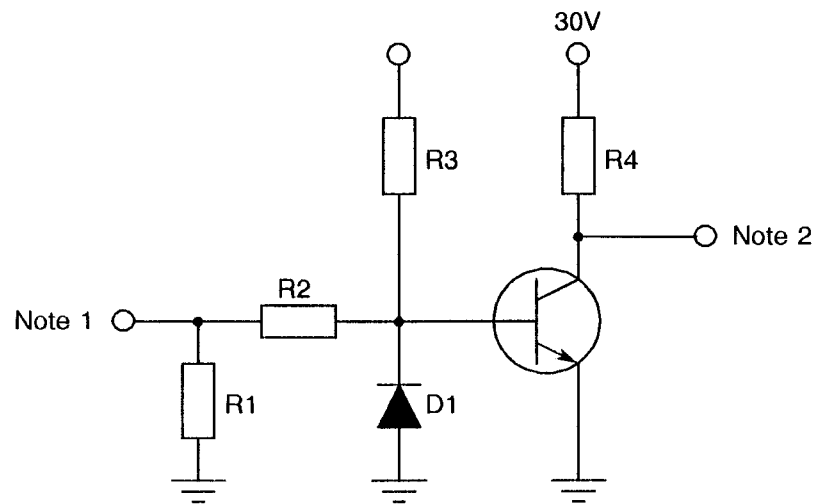


FIGURE 4(b) - TURN-OFF TIME



**NOTES**

1. Pulse rate 150pps, rise time  $\leq 10\text{ns}$ .
2. Oscilloscope: rise time  $\leq 5.0\text{ns}$ , input impedance  $10\text{M}\Omega$ .

**TABLE 4 - PARAMETER DRIFT VALUES**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	CHANGE LIMITS ( $\Delta$ )	UNIT
5	Emitter Cut-off Current	$I_{EBO}$	As per Table 2	As per Table 2	$\pm 20$	nA %
6	Collector Saturation Voltage	$V_{CE(SAT)}$	As per Table 2	As per Table 2	$\pm 50$	mV
9	D.C. Forward Current Transfer Ratio 2	$h_{FE2}$	As per Table 2	As per Table 2	$\pm 25$	%

**TABLE 5 - CONDITIONS FOR BURN-IN AND OPERATING LIFE TESTS**

No.	CHARACTERISTICS	SYMBOL	CONDITIONS	UNIT
1	Case Temperature	$T_{case}$	+ 100(+ 0 - 5)	$^{\circ}C$
2	Collector-Base Voltage	$V_{CB}$	20	V
3	Power Dissipation	$P_{tot}$	80	W
4	Test Method 1039 of MIL-STD-750	-	B	-



- 4.8 ENVIRONMENTAL AND ENDURANCE TESTS (CHARTS IV AND V OF ESA/SCC GENERIC SPECIFICATION NO. 5000)
- 4.8.1 Electrical Measurements on Completion of Environmental Tests  
The parameters to be measured on completion of environmental tests are scheduled in Table 2. The measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.
- 4.8.2 Electrical Measurements at Intermediate Points during Endurance Tests  
The parameters to be measured at intermediate points during endurance tests are scheduled in Table 6 of this specification.
- 4.8.3 Electrical Measurements on Completion of Endurance Tests  
The parameters to be measured on completion of endurance testing are scheduled in Table 6 of this specification. The measurements shall be performed at  $T_{amb} = +22 \pm 3$  °C.
- 4.8.4 Conditions for Operating Life Tests (Part of Endurance Testing)  
The requirements for operating life testing are specified in Section 9 of ESA/SCC Generic Specification No. 5000. The conditions for operating life testing shall be the same as specified in Table 5 for the burn-in test.
- 4.8.5 Electrical Circuits for Operating Life Tests  
Not applicable.
- 4.8.6 Conditions for High Temperature Storage Test (Part of Endurance Testing)  
The requirements for the high temperature storage test are specified in ESA/SCC Generic Specification No. 5000. The conditions for high temperature storage shall be  $T_{amb} = +200(+0 - 5)$  °C.

**TABLE 6 - ELECTRICAL MEASUREMENTS AT INTERMEDIATE POINTS  
AND ON COMPLETION OF ENDURANCE TESTING**

No.	CHARACTERISTICS	SYMBOL	SPEC. AND/OR TEST METHOD	TEST CONDITIONS	LIMITS		UNIT
					MIN.	MAX.	
5	Emitter Cut-off Current	$I_{EBO}$	As per Table 2	As per Table 2	-	100	nA
6	Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	As per Table 2	As per Table 2	-	0.5	V
9	D.C. Forward Current Transfer Ratio 2	$h_{FE2}$	As per Table 2	As per Table 2	80	240	-